



MMBT3904

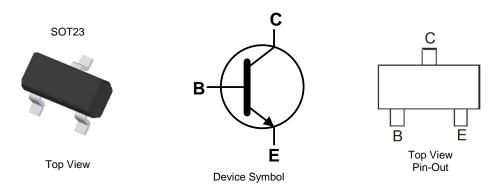
40V NPN SMALL SIGNAL TRANSISTOR IN SOT23

Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMBT3906)
- Ideal for Medium Power Amplification and Switching
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 ⁽²³⁾
- Weight: 0.008 grams (Approximate)



Ordering Information (Notes 4 & 5)

Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
MMBT3904-7-F	Active	AEC-Q101	K1N	7	8	3,000
MMBT3904Q-7-F	Active	Automotive	K1N	7	8	3,000
MMBT3904-13-F	Active	AEC-Q101	K1N	13	8	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

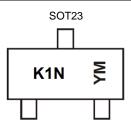
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q10x qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K1N = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: D = 2016) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2014		2015	2016		2017	2018		2019	2020		2021
Code	В		С	D		E	F		G	Н		
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	0	2	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current	lc	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 6)	D	310	mW	
	(Note 7)	P _D	350	11177	
Thermal Decistories, Junction to Ambient	(Note 6)	D	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	R _{θJA}	357	0/11	
Thermal Resistance, Junction to Leads (Note 8)		R _{θJL}	350	°C/W	
Operating and Storage Temperature Range	T _J ,T _{STG}	-55 to +150	°C		

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

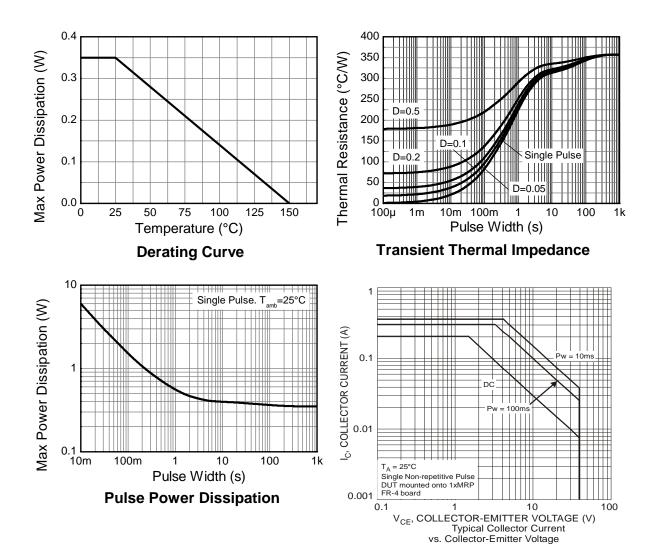
6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air Notes: conditions whilst operating in a steady-state.

7. Same as Note 6, except the device is mounted on 15 mm x 15mm 1oz copper.

Thermal resistance from junction to solder-point (at the end of the leads).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





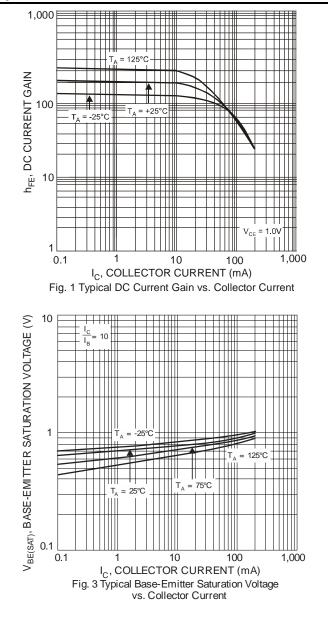
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

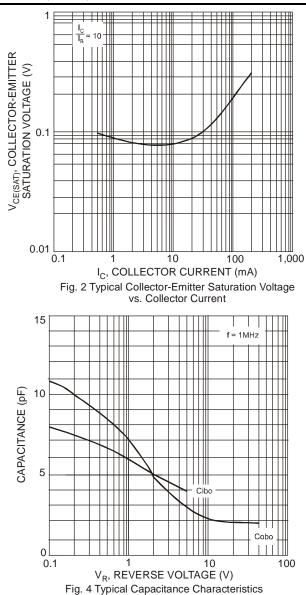
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS					
Collector-Base Breakdown Voltage	BV _{CBO}	60	_	V	$I_{C} = 10 \mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	40	—	V	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	6.0	_	V	$I_{E} = 10 \mu A, I_{C} = 0$
Collector Cut-Off Current	ICEX	_	50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3.0V$
Base Cut-Off Current	I _{BL}	_	50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3.0V$
Emitter Base Cut-Off Current	I _{EBO}	_	50	nA	V _{EB} =6V
Collector-Base Cut-Off Current	I _{CBO}	_	50	nA	V _{CB} =48V
ON CHARACTERISTICS (Note 10)			•	•	F
		40	—		$I_{C} = 100 \mu A, V_{CE} = 1.0 V$
		70			$I_{C} = 1.0 \text{mA}, V_{CE} = 1.0 \text{V}$
DC Current Gain	h _{FE}	100	300	_	$I_{C} = 10 \text{mA}, V_{CE} = 1.0 \text{V}$
		60 30	_		$I_{C} = 50 \text{mA}, V_{CE} = 1.0 \text{V}$
		30	—		$I_{\rm C} = 100 {\rm mA}, V_{\rm CE} = 1.0 {\rm V}$
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	0.20	V	$I_{C} = 10mA, I_{B} = 1.0mA$
•	02(000)		0.30		$I_{\rm C} = 50 {\rm mA}, I_{\rm B} = 5.0 {\rm mA}$
Base-Emitter Saturation Voltage	V _{BE(sat)}	0.65	0.85 0.95	V	$I_{C} = 10mA, I_{B} = 1.0mA$
SMALL SIGNAL CHARACTERISTICS			0.95	<u>i </u>	$I_{\rm C} = 50 {\rm mA}, I_{\rm B} = 5.0 {\rm mA}$
Output Capacitance			4.0	۳E	
	C _{obo}	_	4.0 8.0	pF pF	$V_{CB} = 5.0V, f = 1.0MHz, I_E = 0$
Input Capacitance Input Impedance	C _{ibo}	1.0	8.0 10	μr kΩ	$V_{EB} = 0.5V, f = 1.0MHz, I_C = 0$
Voltage Feedback Ratio	h _{ie}	0.5	8.0	x 10 ⁻⁴	
Small Signal Current Gain	h _{re}	100	400		V _{CE} = 10V, I _C = 1.0mA, f = 1.0kHz
Output Admittance	h _{fe}	1.0	400	 μS	1 = 1.0KHZ
Ouput Autilitatice	h _{oe}	1.0	40	μο	V 20V I 10m A
Current Gain-Bandwidth Product	f _T	300	—	MHz	$V_{CE} = 20V, I_C = 10mA,$ f = 100MHz
Noise Figure	NF	_	5.0	dB	$V_{CE} = 5.0V, I_C = 100\mu A,$
SWITCHING CHARACTERISTICS					$R_S = 1.0k\Omega$, f = 1.0kHz
Delay Time	t _d		35	ns	$V_{CC} = 3.0V, I_{C} = 10mA,$
Rise Time	ta tr		35	ns	$V_{BE(off)} = -0.5V, I_{B1} = 1.0mA$
Storage Time	t _s		200	ns	$V_{CC} = 3.0V, I_{C} = 10mA,$
Fall Time	t _s		50	ns	$I_{B1} = I_{B2} = 1.0 \text{mA}$
	ιf	_	50	115	$1B_1 - 1B_2 = 1.0111A$

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

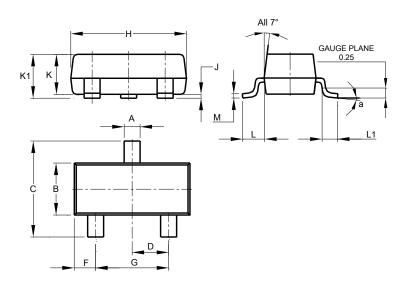






Package Outline Dimensions

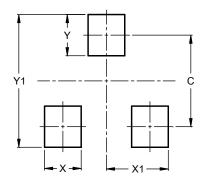
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23						
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
ĸ	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All	Dimens	ions in	mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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